

December 2014

FCP190N65F

N-Channel SuperFET[®] II FRFET[®] MOSFET 650 V, 20.6 A, 190 m Ω

Features

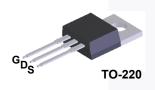
- 700 V @ T_J = 150°C
- Typ. $R_{DS(on)}$ = 168 m Ω
- Ultra Low Gate Charge (Typ. Q_q = 60 nC)
- Low Effective Output Capacitance (Typ. Coss(eff.) = 304 pF)
- · 100% Avalanche Tested
- RoHS Compliant

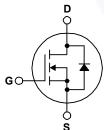
Applications

- · LCD / LED / PDP TV
- Solar Inverter
- · AC DC Power Supply

Description

SuperFET® II MOSFET is Fairchild Semiconductor's brand-new high voltage super-junction (SJ) MOSFET family that is utilizing charge balance technology for outstanding low on-resistance and lower gate charge performance. This technology is tailored to minimize conduction loss, provide superior switching performance, dv/dt rate and higher avalanche energy. Consequently, SuperFET II MOSFET is very suitable for the switching power applications such as PFC, server/telecom power, FPD TV power, ATX power and industrial power applications. SuperFET II FRFET® MOSFET's optimized body diode reverse recovery performance can remove additional component and improve system reliability.





Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter		FCP190N65F	Unit
V _{DSS}	Drain to Source Voltage			650	V
V	Cata to Course Voltage	- DC		±20	V
V _{GSS}	Gate to Source Voltage	- AC	(f > 1 Hz)	±30	V
	Drain Current	- Continuous (T _C = 25°C)		20.6	Α
Drain Current	- Continuous (T _C = 100°C)	/4/	13.1		
I _{DM}	Drain Current	- Pulsed	(Note 1)	61.8	Α
E _{AS}	Single Pulsed Avalanche Energ	Single Pulsed Avalanche Energy (Note 2)			mJ
I _{AR}	Avalanche Current	Avalanche Current (Note 1)		4.0	Α
E _{AR}	Repetitive Avalanche Energy	Repetitive Avalanche Energy (Note 1)			mJ
dv/dt	MOSFET dv/dt			100	Mac
uv/ut	Peak Diode Recovery dv/dt (Note 3)		50	V/ns	
D	Dower Discipation	(T _C = 25°C)		208	W
P_{D}	Power Dissipation	- Derate Above 25°C	- Derate Above 25°C		W/oC
T _J , T _{STG}	Operating and Storage Temper	perating and Storage Temperature Range			°C
T _L	Maximum Lead Temperature for 1/8" from Case for 5 Seconds	Maximum Lead Temperature for Soldering,			°C

Thermal Characteristics

Symbol	Parameter FCP190N65F				
$R_{\theta JC}$	Thermal Resistance, Junction to Case, Max.	0.6	°C/W		
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	C/W		

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FCP190N65F	FCP190N65F	TO-220	Tube	N/A	N/A	50 units

Test Conditions

Min.

Тур.

Max.

Unit

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted. Parameter

Off Charact	teristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 25^{\circ}\text{C}$	650	-	-	W
	Drain to Source Breakdown voltage	$V_{GS} = 0 \text{ V}, I_D = 10 \text{ mA}, T_J = 150^{\circ}\text{C}$	700	-	-	V
$\Delta BV_{DSS} / \Delta T_{J}$	Breakdown Voltage Temperature Coefficient	I _D = 10 mA, Referenced to 25°C	-	0.72	-	V/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 650 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	10	
	Zelo Gale Vollage Diam Current	$V_{DS} = 520 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	60	-	μΑ
I _{GSS}	Gate to Body Leakage Current	V _{GS} = ±20 V, V _{DS} = 0 V	-	-	±100	nA

On Characteristics

Symbol

$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = 2 \text{ mA}$	3	-	5	V
R _{DS(on)}	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 10 A	-	168	190	mΩ
9 _{FS}	Forward Transconductance	V _{DS} = 20 V, I _D = 10 A	-	18	1	S

Dynamic Characteristics

C _{iss}	Input Capacitance	V - 25 V V - 0 V	-	2425	3225	pF
Coss	Output Capacitance	V _{DS} = 25 V, V _{GS} = 0 V, f = 1 MHz	-	2110	2805	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 1011 12	-	105	155	pF
C _{oss}	Output Capacitance	V _{DS} = 380 V, V _{GS} = 0 V, f = 1 MHz	- \	44	-	pF
C _{oss(eff.)}	Effective Output Capacitance	V _{DS} = 0 V to 400 V, V _{GS} = 0 V	-	304	-	pF
Q _{g(tot)}	Total Gate Charge at 10V	V _{DS} = 380 V, I _D = 10 A,	-	60	78	nC
Q_{gs}	Gate to Source Gate Charge	V _{GS} = 10 V	-	12	-	nC
Q_{gd}	Gate to Drain "Miller" Charge	(Note	4) _	25	-	nC
ESR	Equivalent Series Resistance	f = 1 MHz	-	0.6	-	Ω

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		-	25	60	ns
t _r		$V_{DD} = 380 \text{ V}, I_{D} = 10 \text{ A},$	-/	11	32	ns
t _{d(off)}	Turn-Off Delay Time	V_{GS} = 10 V, R_g = 4.7 Ω	-	62	134	ns
t _f	Turn-Off Fall Time	(Note 4)	_//-	4.2	18	ns

Drain-Source Diode Characteristics

Is	Maximum Continuous Drain to Source Diod	Maximum Continuous Drain to Source Diode Forward Current			20.6	Α
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current			-	61.8	Α
V_{SD}	Drain to Source Diode Forward Voltage V _{GS} = 0 V, I _{SD} = 10 A		-	-	1.2	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _{SD} = 10 A,	-	105	-	ns
Q_{rr}	Reverse Recovery Charge $dI_F/dt = 100 \text{ A/}\mu\text{s}$			515	-	nC

- 1. Repetitive rating: pulse width limited by maximum junction temperature.
- 2. I_{AS} = 4 A, R_G = 25 Ω , starting T_J = 25°C.
- 3. I $_{SD} \leq$ 10 A, di/dt \leq 200 A/µs, V $_{DD} \leq$ 380 V, starting T $_{J}$ = 25°C.
- 4. Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

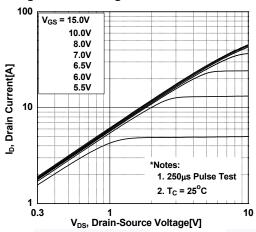


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

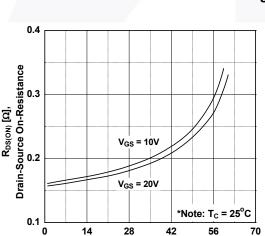


Figure 5. Capacitance Characteristics

ID, Drain Current [A]

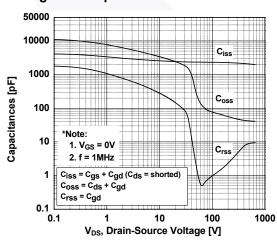


Figure 2. Transfer Characteristics

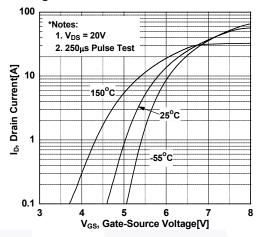


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

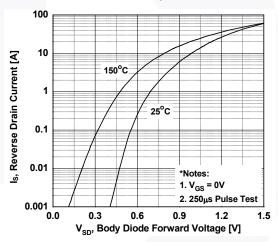
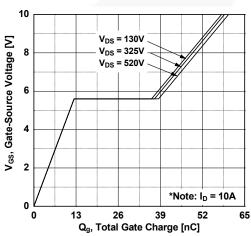


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

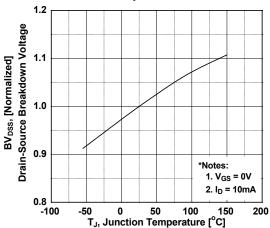


Figure 9. Maximum Safe Operating Area

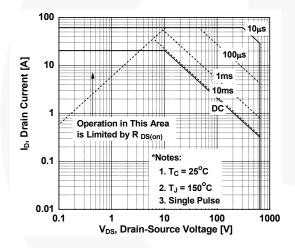


Figure 11. Eoss vs. Drain to Source Voltage

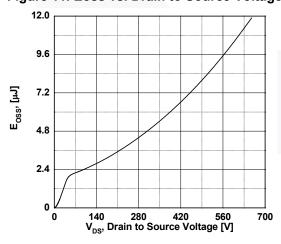


Figure 8. On-Resistance Variation vs. Temperature

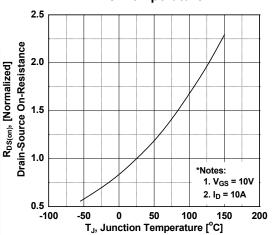
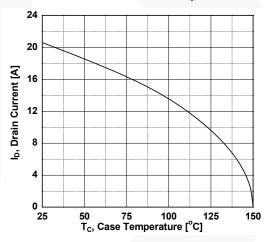
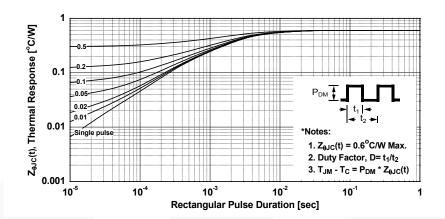


Figure 10. Maximum Drain Current vs. Case Temperature



Typical Performance Characteristics (Continued)

Figure 12. Transient Thermal Response Curve



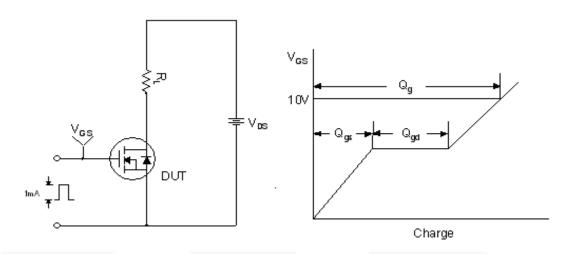


Figure 13. Gate Charge Test Circuit & Waveform

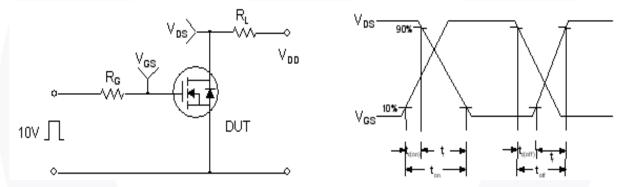


Figure 14. Resistive Switching Test Circuit & Waveforms

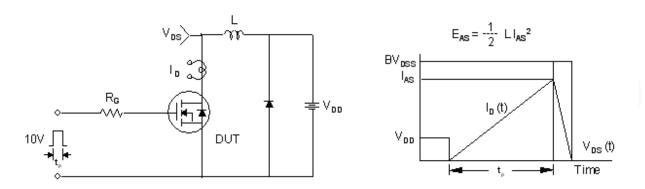


Figure 15. Unclamped Inductive Switching Test Circuit & Waveforms

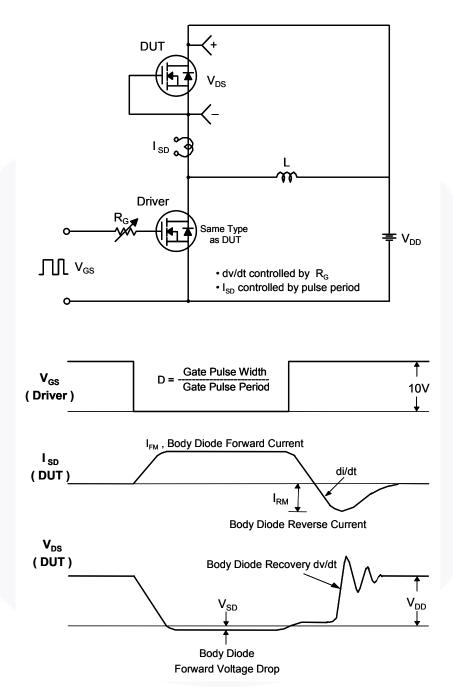
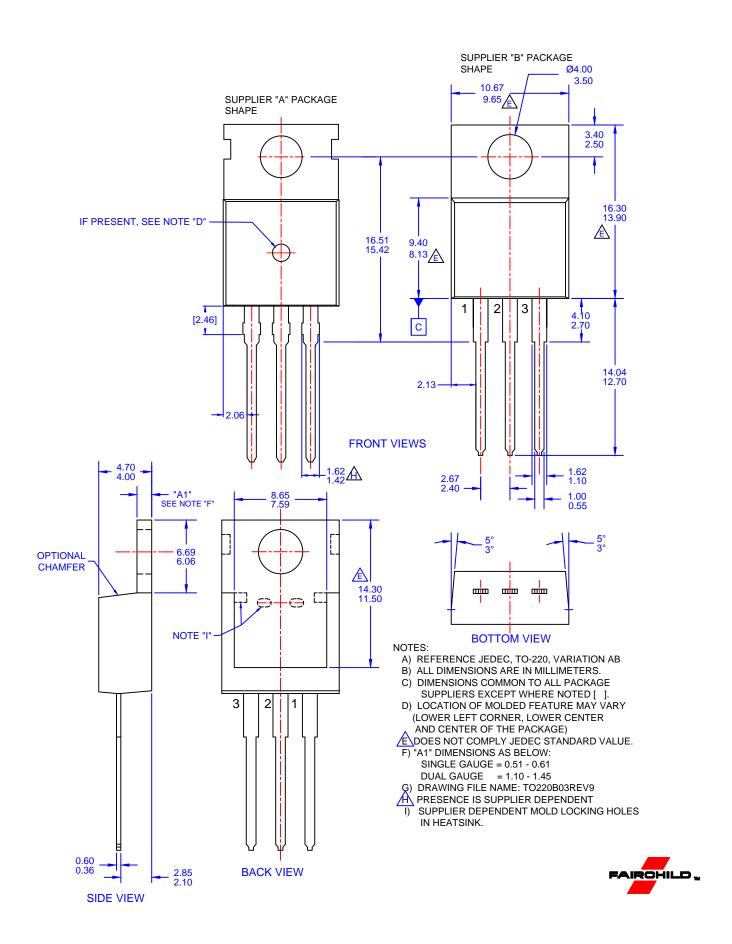


Figure 16. Peak Diode Recovery dv/dt Test Circuit & Waveforms







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Definition of Terms		
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